

High-voltage soft-recovery rectifier

BY584

FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Soft-recovery switching characteristics
- Compact construction.

APPLICATIONS

- Grid 2 supply in colour television picture tubes
- High-voltage applications for:
 - High frequencies
 - Switching applications.

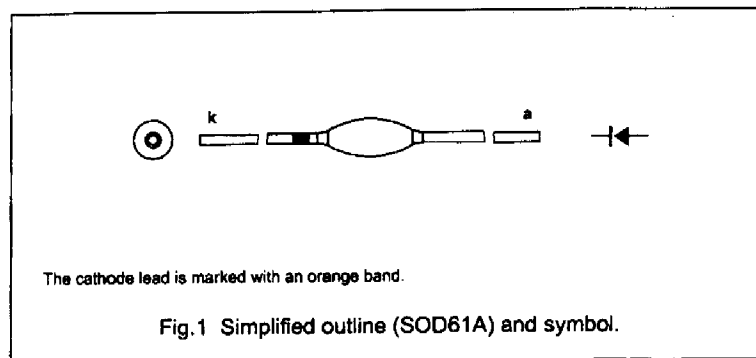
DESCRIPTION

Rugged glass package, using a high temperature alloyed construction.

This package is hermetically sealed and fatigue free as coefficients of

expansion of all used parts are matched.

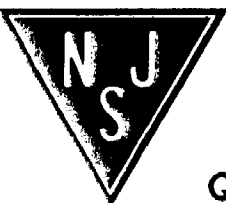
The package is designed to be used in an insulating medium such as resin, oil or SF6 gas.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_{RSM}	non-repetitive peak reverse voltage		-	1800	V
V_{RRM}	repetitive peak reverse voltage		-	1800	V
V_{RW}	working reverse voltage		-	1500	V
$I_{F(AV)}$	average forward current	averaged over any 20 ms period; $T_{ip} = 25\text{ }^{\circ}\text{C}$; lead length = 10 mm; see Fig.2; see also Fig.4	-	85	mA
		averaged over any 20 ms period; $T_{amb} = 60\text{ }^{\circ}\text{C}$; PCB mounting (see Fig.6); see Fig.3; see also Fig.4	-	50	mA
I_{FRM}	repetitive peak forward current		-	800	mA
I_{FSM}	non-repetitive peak forward current	$t \leq 10\text{ ms}$; half sinewave; $T_j = T_{j\text{max}}$ prior to surge; $V_R = V_{RW\text{max}}$	-	5	A
T_{stg}	storage temperature		-65	+120	$^{\circ}\text{C}$
T_j	junction temperature		-65	+120	$^{\circ}\text{C}$



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ELECTRICAL CHARACTERISTICS $T_j = 25\text{ }^\circ\text{C}$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_F	forward voltage	$I_F = 100\text{ mA}$; $T_j = T_{j\text{ max}}$; see Fig.5	-	-	8.5	V
I_R	reverse current	$V_R = V_{RW\text{ max}}$; $T_j = T_{j\text{ max}}$	-	-	3	μA
Q_r	recovery charge	when switched from $I_F = 100\text{ mA}$ to $V_R \geq 100\text{ V}$ and $di_F/dt = -200\text{ mA}/\mu\text{s}$; see Fig.7	-	-	1	nC
t_f	fall time	when switched from $I_F = 100\text{ mA}$ to $V_R \geq 100\text{ V}$ and $di_F/dt = -200\text{ mA}/\mu\text{s}$; see Fig.7	100	-	-	ns
t_{rr}	reverse recovery time	when switched from $I_F = 100\text{ mA}$ to $V_R \geq 100\text{ V}$ and $di_F/dt = -200\text{ mA}/\mu\text{s}$; see Fig.7	-	200	-	ns
C_d	diode capacitance	$V_R = 0\text{ V}$; $f = 1\text{ MHz}$	-	2	-	pF

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length = 10 mm	100	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	155	K/W